

SMF501C - SMF507C

SURFACE MOUNT FAST RECOVERY RECTIFIER DIODES

VOLTAGE RANGE: 50V-1000 V CURRENT: 5.0 A

Features

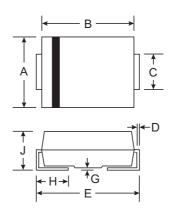
- Glass Passivated Die Construction
- Fast Recovery Time for High Efficiency
- Low Forward Voltage Drop and High Current Capability
- Ideally Suited for Automatic Assembly
- Plastic Material: UL Flammability
 Classification Rating 94V-0

Mechanical Data

- Case: SMC(DO-214AB), Molded Plastic
- Terminals: Solder Plated Terminal -Solderable per MIL-STD-202, Method 208
- Polarity: Cathode Band or Cathode Notch
- Marking: Type Number
- Weight: 0.21 grams (approx.)







SMC/DO-214AB							
Dim	Min	Max					
Α	5.59	6.22					
В	6.60	7.11					
С	2.75	3.18					
D	0.15	0.31					
E	7.75	8.13					
G	0.10	0.20					
Н	0.76	1.52					
J	2.00	2.62					
All Dimensions in mm							

Maximum Ratings and Electrical Characteristics @ T_A = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	SMF501C	SMF502C	SMF503C	SMF504C	SMF505C	SMF506C	SMF507C	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	50	100	200	400	600	800	1000	V
RMS Reverse Voltage	V _{R(RMS)}	35	70	140	280	420	560	700	٧
Average Rectified Output Current @ T _T = 75°C	I _O	5.0							Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave Superimposed on Rated Load (JEDEC Method)	I _{FSM}	150						Α	
Forward Voltage @ I _F = 5.0A	V_{FM}	1.3						٧	
Peak Reverse Current @ T _A = 25°C at Rated DC Blocking Voltage @ TA = 125°C	I _{RM}	5.0 100							μА
Maximum Recovery Time (Note 3)	t _{rr}	150 250 5		00	ns				
Typical Junction Capacitance (Note 2)		78							pF
Typical Thermal Resistance Junction to Terminal (Note 1)	$R_{\theta JT}$	л 50			K/W				
Operating and Storage Temperature Range	$T_{j,}T_{STG}$	G -65 to +150					°C		

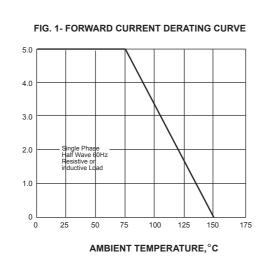
Notes: 1. Thermal resistance: junction to terminal, unit mounted on PC board with 5.0 mm² (0.013 mm thick) copper pad as heat sink.

- 2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.
- 3. Reverse recovery test conditions: $I_F = 0.5A$, $I_R = 1.0A$, $I_{rr} = 0.25A$. See figure 5.



RATINGS AND CHARACTERISTIC CURVES SMF501C THRU SMF507C





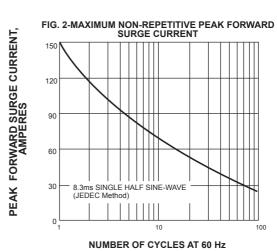
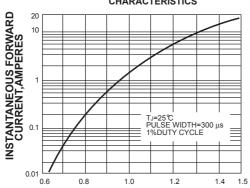


FIG. 3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS



1,000 100

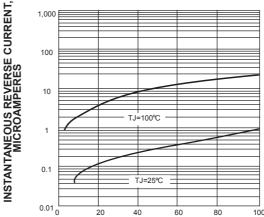


FIG. 4-TYPICAL REVERSE CHARACTERISTICS

INSTANTANEOUS FORWARD VOLTAGE, **VOLTS**

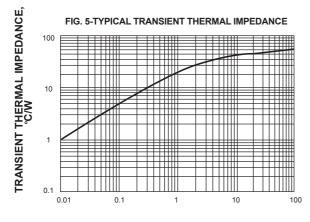
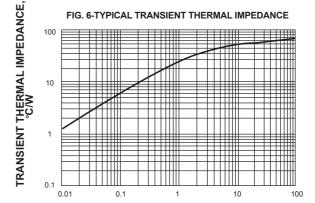


FIG. 6-TYPICAL TRANSIENT THERMAL IMPEDANCE

PERCENT OF PEAK REVERSE VOLTAGE,%



t,PULSE DURATION,sec.

t,PULSE DURATION,sec.

单击下面可查看定价,库存,交付和生命周期等信息

>>SUNMATE(森美特)